

# VB026BSP

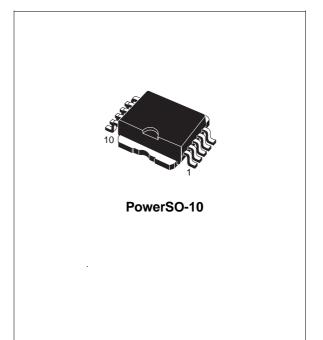
## HIGH VOLTAGE IGNITION COIL DRIVER POWER IC

TYPE	V <sub>cl</sub>	Ici	ld
VB026BSP	360 V	9 A	100 mA

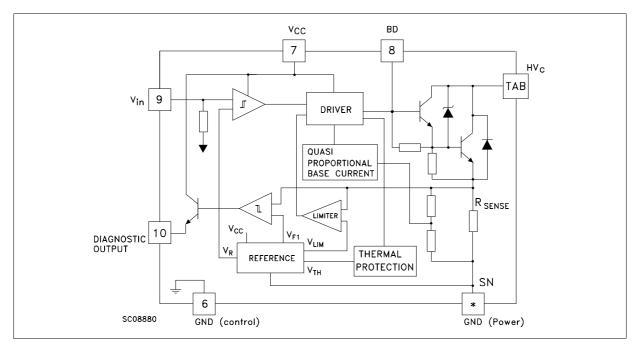
- PRIMARY COIL VOLTAGE INTERNALLY SET
- COIL CURRENT LIMIT INTERNALLY SET
- LOGIC LEVEL COMPATIBLE INPUT
- DRIVING CURRENT QUASI PROPORTIONAL TO COLLECTOR CURRENT
- SINGLE FLAG-ON COIL CURRENT

#### DESCRIPTION

The VB026BSP is a high voltage power integrated circuit made using STMicroelectronics VIPower Technology, with vertical current flow power darlington and logic level compatible driving circuit. Built-in protection circuits for coil current limiting and collector voltage clamping allows the VB026BSP to be used as a smart, high voltage, high current interface in advanced electronic ignition systems.



#### **BLOCK DIAGRAM**



### VB026BSP

#### ABSOLUTE MAXIMUM RATING

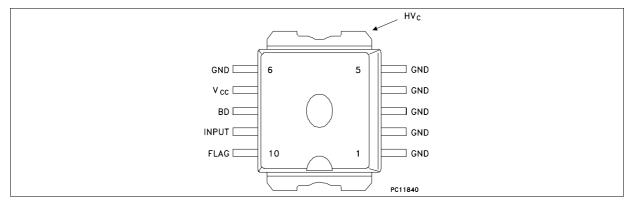
Symbol	Parameter	Value	Unit
HVc	Collector Voltage (Internally Limited)	-0.3 to V <sub>clamp</sub>	V
Ic	Collector Current (Internally Limited)	10	Α
I <sub>C(gnd)</sub>	DC Current on Emitter Power	± 10.5 (*)	Α
Vcc	Driving Stage Supply Voltage	-0.3 to 7	V
ls	Driving Circuitry Supply Current	± 200	mA
I <sub>s(gnd)</sub>	DC Current on Ground Pin	± 1	Α
Vin	Input Voltage	-0.3 to VCC + 0.3	V
lin	Maximum Input Current	100	mA
f <sub>in</sub>	Logic Input Frequency in Operative Mode	DC to 150	Hz
V <sub>out(flag)</sub>	Output Voltage Primary Threshold Current Level	-0.3 to VCC + 0.3	V
I <sub>out(flag)</sub>	Flag Output Current	100	mA
I <sub>BD</sub>	Input Darlington Base Current	150	mA
$V_{BD}$	Input Darlington Base Voltage	Internally Limited	V
Pmax	Power Dissipation (TC = $105 ^{\circ}$ C)	TBD	W
E <sub>s/b</sub>	Clamped Energy During Output Power Clamping	300	mJ
Vesd	ESD Voltage (HVC Pin)	± 4	K۷
$V_{\text{ESD}}$	ESD Voltage (Other Pins)	± 2	K٧
Tj	Operating Junction Temperature	-40 to 150	°C
T <sub>stg</sub>	Storage Temperature Range	-55 to 150	°C

## THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction Case	(MAX)	1.2	°C/W
R <sub>thj-h</sub>	Thermal Resistance Junction Heatsink with FR4	(MAX)	TBD (*)	°C/W
T <sub>sold</sub>	Lead Temperature During Soldering	(MAX)	TBD (*)	°C

(\*) see application note AN515 on VIPower databook 1<sup>st</sup> edition

#### **CONNECTION DIAGRAM**



#### **PIN FUNCTION**

No	NAME	FUNCTION			
1-5	GND	Emitter Power Ground			
6	GND	Control Ground (*)			
7	Vcc	Logic Supply Voltage			
8	BD	Base Darlington			
9	INPUT	Logic Input Channel (Internal Pull-down)			
10	FLAG	Diagnostic Output Signal (Open Emitter)			
TAB	HVC	Primary Coil Output Driver (Open Collector)			

(\*) Pin 6 must be connected to pins 1-5 externally

# **ELECTRICAL CHARACTERISTICS** ( $5.3V < V_b < 24V$ ; $V_{CC} = 5 V \pm 10\%$ ; $-40^{\circ}C < T_j < 125^{\circ}C$ ; $R_{coil} = 580 \text{ m}\Omega$ ; $L_{coil} = 3.75 \text{ mH}$ ; unless otherwise specified; see note 1)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>cl</sub>	High Voltage Clamp	$I_{coil} = 6.5 \text{ A}$	320	360	420	V
$V_{ce(sat)}$	Saturation Voltage of The Power Stage	$I_c = 7.5 \text{ A};  V_{in} = 4V$			TBD	V
I <sub>d(stdby)</sub>	Stand-by Supply Current	IN = OFF			10	mA
I <sub>CC</sub>	DC Logic Current				40	mA
I <sub>CC(peak)</sub>	Peak DC Logic Current During On Phase	$I_c = 7.5 \text{ A}$ (see figure 1)			TBD	mA
Vcc	DC Logic Voltage		4.5		5.5	V
I <sub>cl</sub>	Coil Current Limit	-40°C < T <sub>j</sub> < 125°C (see note 2 and figure 1)	9		11	A
I <sub>c(leak)</sub>	Output leakage Current	IN = OFF V <sub>HVC</sub> = 24V			0.8	mA
I <sub>C(infl)</sub>	Collector Current with Floating Input	$ \begin{array}{ll} VCC = 5 \ V & VBat = 13.5 \ V \\ R_{LOAD} = 1K\Omega; & Input \ Floating \end{array} $			0.8	mA
$T_{shdw}$	Thermal Temperature Output Current Control	OUT = ON (see figure 2)	150		(*)	°C
$V_{\text{inH}}$	High Level Input Voltage	$V_{CC} = 4.5V$	4		V <sub>CC</sub>	V
VinL	Low Level Input Voltage	V <sub>CC</sub> = 5.5V	-0.3		0.8	V

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Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>in(hys)</sub>	Input Threshold Hysteresis		0.4			V
l <sub>inH</sub>	High Level Input Current	V <sub>in</sub> = 4 V			100	μA
l <sub>inL</sub>	Low Level Input Current	V <sub>in</sub> = 0.8 V			-100	μA
l <sub>inpd</sub>	Input Active Pull-Down	$V_{in} = 4 V$	10		100	μA
$V_{diagH}$	High Level Flag Output Voltage	$R_{EXT} = 22 \text{ K}\Omega$ $C_{EXT} = 1 \text{ nF}$ (see note 3)	Vcc-1		Vcc	V
$V_{\text{diagL}}$	Low Level Flag Output Voltage	$R_{EXT} = 22 K\Omega$ $C_{EXT} = 1 nF$ (see note 3)			0.5	V
I <sub>diagTH</sub>	Coil Current Level Threshold	$T_j = 25^{\circ}C$ (see figure 1)	6.15	6.5	6.85	A
I <sub>diagTD</sub>	Coil Current Level Threshold Drift	(see figure 3)				
I <sub>diag</sub>	High Level Flag Output Current	$I_{C} > I_{diagTH}$ $V_{diag} = 3V$	0.5	TBD		mA
l <sub>diag(leak)</sub>	Leakage Current On Flag Output	$V_{in} = LOW  V_{CC} = 5.5V$			10	μA
VF	Antiparallel Diode Forward Voltage	I <sub>c</sub> = -1 A			2	V
$E_{s/b}$	Single Pulse Avalanche Energy	$I_C = 8A$ $L_C = 6 mH$ (see figure 4)	180			mJ
t <sub>pHL</sub>	Turn-on Delay Time of Coil Current	$\label{eq:Rc} \begin{array}{l} R_{c} = 0.5 \ \Omega \ \ L_{c} = 3.75 \ \text{mH} \\ (\text{see figure 5}) \end{array}$		TBD		μs
t <sub>pLH</sub>	Turn-off Delay Time of Coil Current	$R_c = 0.5 \ \Omega$ $L_c = 3.75 \ mH$ $I_c = 6.5A$ (see figure 5)		TBD		μs

#### ELECTRICAL CHARACTERISTICS (continued)

Note 1: Parametric degradation are allowed with  $5.3 < V_b < 10V$  and  $V_b > 24V$ .

Note 2: The primary  $\ddot{coil}$  current value  $I_{cl}$  must be measured 1ms after desaturation of the power stage.

Note 3: No Internal Pull-Down

(\*) Internally limited

#### PRINCIPLE OF OPERATION

The VB026BSP is mainly intended as a high voltage power switch device driven by a logic level input and interfaces directly to a high energy electronic ignition coil.

The input Vin of the VB026BSP is fed from a low power signal generated by an external controller that determines both dwell time and ignition point. During Vin high ( $\geq 4V$ ) the VB026BSP increases current in the coil to the desired, internally set current level.

After reaching this level, the coil current remains constant until the ignition point, that corresponds to the transition of Vin from high to low (typ. 1.9V threshold).

During the coil current switch-off, the primary

voltage HVc is clamped at an internally set value Vcl, typically 360V.

The transition from saturation to desaturation, coil current limiting phase, must have the ability to accomodate an overvoltage. A maximum overshoot of 20V is allowed.

#### FEEDBACK

When the collector current exceeds 6.5A, the feedback signal is turned high and it remains so, until the input voltage is turned-off.

#### OVERVOLTAGE

The VB026BSP can withstand the following transients of the battery line:

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- $-100V/2msec (R_i = 10 \Omega)$
- +100V/0.2msec ( $R_i = 10 \Omega$ )
- +50V/400msec (Ri = 4.2  $\Omega,$  with VIN = 3 V)

4/7

Fig. 1 Main Waveforms During On Phase

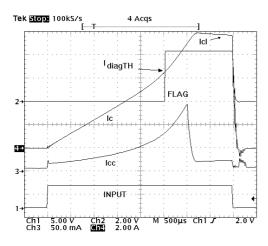


Fig. 3 Flag Current Versus Temperature

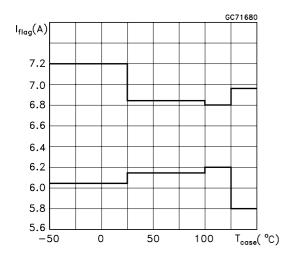
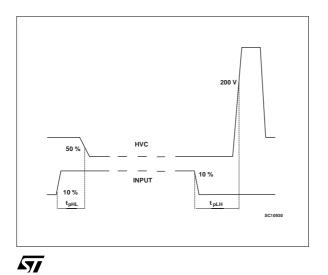
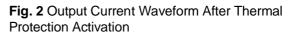


FIG. 5 Propagation Times Definitions.





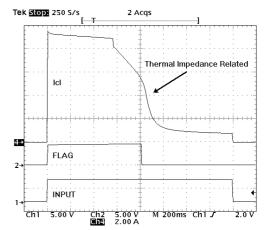
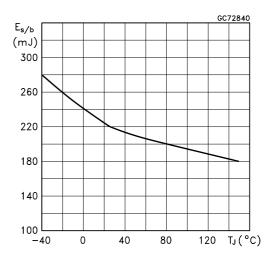
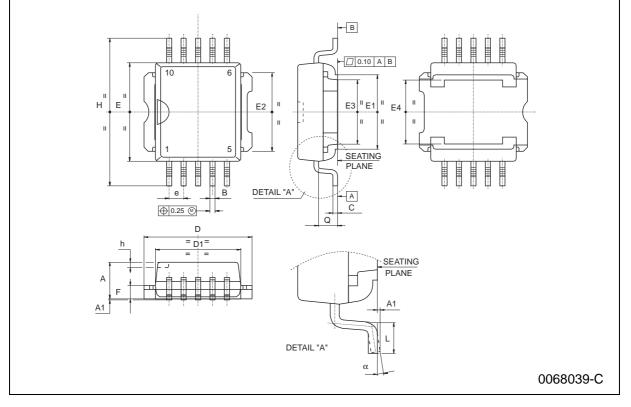


FIG. 4 Single Pulse Typical Es/b Curve



DIM.		mm		inch		
Divi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	3.35		3.65	0.132		0.144
A1	0.00		0.10	0.000		0.004
В	0.40		0.60	0.016		0.024
С	0.35		0.55	0.013		0.022
D	9.40		9.60	0.370		0.378
D1	7.40		7.60	0.291		0.300
Е	9.30		9.50	0.366		0.374
E1	7.20		7.40	0.283		0.291
E2	7.20		7.60	0.283		0.300
E3	6.10		6.35	0.240		0.250
E4	5.90		6.10	0.232		0.240
е		1.27			0.050	
F	1.25		1.35	0.049		0.053
Н	13.80		14.40	0.543		0.567
h		0.50			0.002	
L	1.20		1.80	0.047		0.071
q		1.70			0.067	





57

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57